

3.3V/5V 3.2Gbps CML LOW-POWER LIMITING POST AMPLIFIER w/TTL SD

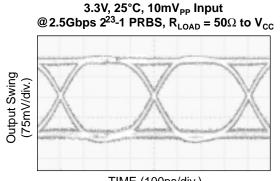
FEATURES

- Multi-Rate up to 3.2Gbps operation
- Wide gain-bandwidth product
- 38dB differential gain
- 2.2GHz 3dB bandwidth
- **Low noise 50** Ω CML data outputs
 - 800mV_{pp} output swing
 - 60ps edge rates
 - 5ps_{rms} typ. random jitter
 - 15ps_{pp} typ. deterministic jitter
- Chatter-free Signal Detect (SD) output
 - 4.6dB electrical hysteresis
 - OC-TTL output with internal 5k Ω pull-up resistor
- Programmable SD sensitivity using single external resistor
- Internal 50Ω data input termination
- TTL EN input allows feedback from SD
- Wide operating range
 - Single 3.3V ±10% or 5V ±10% power supply
 - –40°C to +85°C industrial temperature range
- Available in tiny 10-pin MSOP (3mm) and 16-pin MLF[™] (3mm × 3mm) packages
- NOT RECOMMENDED for New Designs!

APPLICATIONS

- 1.25Gbps and 2.5Gbps Gigabit Ethernet
- 1.062Gbps and 2.125Gbps Fibre Channel
- 155Mbps, 622Mbps, 1.25Gbps and 2.5Gbps SONET/SDH
- Gigabit interface converter (GBIC)
- Small form factor (SFF) and small form factor pluggable (SFP) transceivers
- Parallel 10G Ethernet
- High-gain line driver and line receiver

TYPICAL PERFORMANCE



TIME (100ps/div.)

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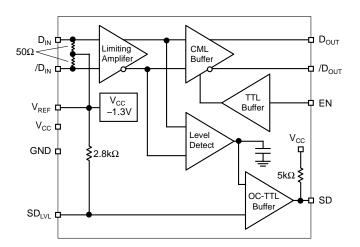
The SY88983V low-power limiting post amplifier is designed for use in fiber optic receivers. The device connects to typical transimpedance amplifiers (TIAs). The linear signal output from TIAs can contain significant amounts of noise and may vary in amplitude over time. The SY88983V quantizes these signals and outputs typically 800mV_{pp} voltage-limited waveforms.

The SY88983V operates from a single +3.3V \pm 10% or +5V \pm 10% power supply, over the industrial temperature of -40°C to +85°C. With its wide bandwidth and high gain, signals with data rates up to 3.2Gbps and as small as 10mV_{pp} can be amplified to drive devices with CML inputs or AC-coupled PECL inputs.

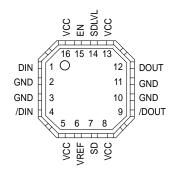
The SY88983V generates a signal detect (SD) opencollector TTL output with internal $5k\Omega$ pull-up resistor. A programmable signal detect level set pin (SD_{LVL}) sets the sensitivity of the input amplitude detection. SD asserts high if the input amplitude rises above the threshold set by SD_{LVL} and de-asserts low otherwise. SD can be fed back to the enable (EN) input to maintain output stability under a lossof-signal condition. EN de-asserts the true output signal without removing the input signal. Typically, 4.6dB SD hysteresis is provided to prevent chattering.

All support documentation can be found on Micrel's web site at www.micrel.com.

FUNCTIONAL BLOCK DIAGRAM



PACKAGE/ORDERING INFORMATION



Ordering Information

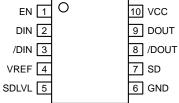
Part Number	Package Type	Operating Range	Package Marking
SY88983VKI	K10-1	Industrial	983V
SY88983VKITR ⁽¹⁾	K10-1	Industrial	983V
SY88983VMI	MLF-16	Industrial	983V
SY88983VMITR ⁽¹⁾	MLF-16	Industrial	983V

Note:

1. Tape and Reel.



16-Pin MLF™ (MLF-16)



10-Pin MSOP (K10-1)

PIN DESCRIPTION

Pin Number (MSOP)	Pin Number (MLF™)	Pin Name	Туре	Pin Function
1	15	EN	TTL Input: Default is high.	Enable: De-asserts true data output when low.
2, 3	1, 4	DIN, /DIN	Differential Data Input	Differential data input. Each pin internally terminates to V_{REF} through 50 Ω .
4	6	VREF		Reference Voltage: Bypass with 0.01 μ F low ESR capacitor from V _{REF} to V _{CC} to stabilize SD _{LVL} and V _{REF} .
5	14	SDLVL	Input: Default is maximum sensitivity.	Signal Detect Level Set: A resistor from this pin to V_{CC} sets the threshold for the data input amplitude at which the SD output will be asserted.
6	2, 3, 10, 11, Exposed Pad	GND	Ground	Device ground. Exposed pad must be connected to same potential as ground pins for MLF-16.
7	7	SD	Open-Collector: TTL Output with internal 5kΩ pull-up resistor.	Signal Detect: Asserts high when the data input amplitude rises above the threshold set by SD _{LVL} .
8, 9	9, 12	DOUT, /DOUT	Differential CML Output	Differential data output.
10	5, 8, 13, 16	VCC	Power Supply	Positive power supply. Bypass with 0.1μ F $ 0.01\mu$ F low ESR capacitors. 0.01μ F capacitors should be as close to V _{CC} pins as possible.

Absolute Maximum Ratings⁽¹⁾

Supply Voltage (V _{CC})	0V to +7.0V
EN, SD _{LVL} Voltage	0 to V _{CC}
D _{IN} , /D _{IN} Current	
D _{OUT} , /D _{OUT} Current	
SD Current	±5mA
V _{REF} Current	±1mA
Storage Temperature (T _S)	–65°C to +150°C
Lead Temperature (soldering, 10 sec.).	220°C

Operating Ratings⁽²⁾

Supply Voltage (V _{CC})	+3.0V to +3.6V or +4.5V to +5.5V
Ambient Temperature (T _A)	
Junction Temperature (T _J)	–40°C to +120°C
Package Thermal Resistance ⁽³⁾	
MLF™	
(θ _{JA}) Still-Air (ψ _{JB})	61°C/W
(ψ_{JB})	38°C/W
MSOP	
(θ_{JA}) Still-Air	113°C/W
(ψ_{JB})	74°C/W

DC ELECTRICAL CHARACTERISTICS

$V_{CC} = 3.0V$ to 3.6V or 4.5V to 5.5V; $R_{I,OAD} = 50\Omega$ to V_{CC} ; $T_A = -40^{\circ}$ C to +85°C; typical values at $V_{CC} = 3.3V$, $T_A = 25^{\circ}$) C
$v_{CC} = 3.0$ to 3.0 or 4.5 to 3.5 v, $N_{IOAD} = 3022$ to v_{CC} , $T_A = -40$ C to $+05$ C, typical values at $v_{CC} = 3.5$ v, $T_A = 25$	0.

Symbol	Parameter	Condition	Min	Тур	Max	Units
I _{CC}	Power Supply Current ⁽⁴⁾	3.3V 5V		19 21	28 31	mA mA
I _{CC}	Power Supply Current ⁽⁵⁾	3.3V 5V		32 38	53 58	mA mA
V _{REF}	V _{REF} Voltage			V _{CC} –1.3		V
SD _{LVL}	SD _{LVL} Level		V _{REF}		V _{CC}	V
V _{OH}	Output HIGH Voltage	Note 6	V _{CC} -0.020	V _{CC} -0.005	V _{CC}	V
V _{OL}	Output LOW Voltage	Note 6		V _{CC} -0.400	V _{CC} -0.275	V
V _{OFFSET}	Differential Output Offset				±80	mV
Z _O	Single-Ended Output Impedance		40	50	60	Ω
ZI	Single-Ended Input Impedance		40	50	60	Ω

TTL DC ELECTRICAL CHARACTERISTICS

 V_{CC} = 3.0V to 3.6V or 4.5V to 5.5V; R_{LOAD} = 50 Ω to V_{CC} ; T_A = -40°C to +85°C; typical values at V_{CC} = 3.3V, T_A = 25°C.

Symbol	Parameter	Condition	Min	Тур	Max	Units
V _{OH}	SD Output HIGH Level	Sourcing 100µA	2.4		V _{CC}	V
V _{OL}	SD Output LOW Level	Sinking 2mA			0.5	V
V _{IH}	EN Input HIGH Voltage		2.0			V
V _{IL}	EN Input LOW Voltage				0.8	V
I _{IH}	EN Input HIGH Current	$V_{IN} = 2.7V$ $V_{IN} = V_{CC}$			20 100	μA μA
I	EN Input LOW Current	V _{IN} = 0.5V	-0.3			mA

Notes:

1. Permanent device damage may occur if "Absolute Maximum Ratings" are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to "Absolute Maximum Ratings" conditions for extended periods may affect device reliability.

2. The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.

- 3. Thermal performance assumes use of 4-layer PCB. If applicable, exposed pad must be soldered (or equivalent) to the device's most negative potential on the PCB.
- 4. Excludes current of CML output stage. See "Detailed Description."

5. Total device current with no output load.

6. Output levels are based on a 50Ω to V_{CC} load impedance. If the load impedance is different, the output level will be changed.

AC ELECTRICAL CHARACTERISTICS

$V_{CC} = 3.0V$ to 3.6V or 4.5V to 5.5V; R_{LOAI}	500 to V/ . T 4000		A A V T A C A C A C A C A C A C A C A C A C A
$V_{} = 311710367074571055778$	$= 5000 \text{ fo } V_{-} = 1 = -40^{\circ}$	to +85°L . typical values at V	
$V_{CC} = 0.00$ to 0.00 or ± 0.00 to 0.00, 10000	3 = 0.032 10 V CC, 1 A = +0.0		$-0.00, 1_{\Lambda} - 200$

Symbol	Parameter	Condition	Min	Тур	Max	Units
HYS	SD Hysteresis	Note 7	2	4.6	8	dB
PSRR	Power Supply Rejection Ratio			35		dB
t _{OFF}	SD Release Time			0.1	0.5	μs
t _{ON}	SD Assert Time			0.2	0.5	μs
t _r , t _f	Differential Output Rise/Fall Time (20% to 80%)	Note 8		60	120	ps
t _{JITTER}	Deterministic Random	Note 9		15 5		ps _{p-p} ps _{rms}
V _{ID}	Differential Input Voltage Swing		10		1800	mV _{p-p}
V _{OD}	Differential Output Voltage Swing	Note 10	550	800		mV _{p-p}
V _{SR}	SD Sensitivity Range	Note 11	10		50	mV _{p-p}
A _{V(Diff)}	Differential Voltage Gain		32	38		dB
B_3dB	3dB Bandwidth			2.2		GHz
S ₂₁	Single-Ended Small Signal-Gain		26	32		dB

Notes:

7. Electrical signal.

8. With input signal V_{ID} > 50mV $_{p\mbox{-}p}$ and 50 Ω load.

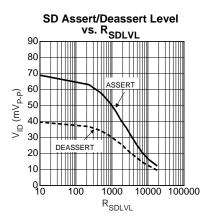
9. Deterministic jitter measured using K28.5 pattern at 2.488Gbps, $V_{ID} = 10mV_{p-p}$. Random jitter measured using K28.7 pattern at 2.488Gbps, $V_{ID} = 10mV_{p-p}$.

10. Input is a 200MHz square wave, t_r < 300ps, 50 Ω load. $V_{ID} \ge 14mV_{p\text{-}p\text{-}}$

11. This is the detectable range of input amplitudes that can de-assert SD. The input amplitude to assert SD is 2–8dB higher than the de-assert amplitude. See "Typical Operating Characteristics" for a graph showing how to choose a particular R_{SDLVL} for a particular SD de-assert, and its associated assert, amplitude.

TYPICAL OPERATING CHARACTERISTICS

 V_{CC} = 3.3V, GND = 0V, T_A = 25°C $\,$ unless otherwise stated.



DETAILED DESCRIPTION

The SY88983V low power limiting post amplifier operates from a single +3.3V or +5V power supply, over temperatures from –40°C to +85°C. Signals with data rates up to 3.2Gbps and as small as $10mV_{p-p}$ can be amplified. Figure 1 shows the allowed input voltage swing. The SY88983V generates an SD output, allowing feedback to EN for output stability. $SD_{I,VI}$ sets the sensitivity of the input amplitude detection.

Input Amplifier/Buffer

The SY88983V's inputs are internally terminated with 50Ω to V_{REF}. Unless they are not affected by this internal termination scheme, upstream devices need to be AC-coupled to the SY88983V's inputs. Figure 2 shows a simplified schematic of the input stage.

The high sensitivity of the input amplifier allows signals as small as $10mV_{p-p}$ to be detected and amplified. The input amplifier allows input signals as large as $1800mV_{p-p}$. Input signals are linearly amplified with a typically 38dB differential voltage gain. Since it is a limiting amplifier, the SY88983V outputs typically $800mV_{p-p}$ voltage-limited waveforms for input signals that are greater than $10mV_{p-p}$. Applications requiring the SY88983V to operate with high-gain should have the upstream TIA placed as close as possible to the SY88983V's input pins to ensure the best performance of the device.

Output Buffer

The SY88983V's CML output buffer is designed to drive 50 Ω lines. The output buffer requires appropriate termination for proper operation. An external 50 Ω resistor to V_{CC} or equivalent for each output pin provides this. Figure 3 shows a simplified schematic of the output stage and includes an appropriate termination method. Of course, driving a downstream device with a CML input that is internally terminated with 50 Ω to V_{CC} eliminates the need for external termination. As noted in the previous section, the amplifier outputs typically 800mV_{p-p} waveforms across 25 Ω total loads. The output buffer, thus, switches typically 16mA tail-current. Figure 4 shows the power supply current measurement, which excludes the 16mA tail-current.

Signal Detect

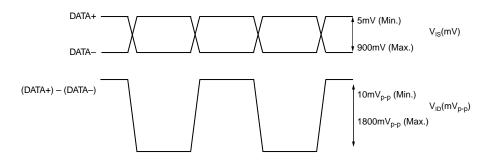
The SY88983V generates a chatter-free signal detect (SD) open-collector TTL output with internal $5k\Omega$ pull-up resistor as shown in Figure 5. SD is used to determine that the input amplitude is large enough to be considered a valid input. SD asserts high if the input amplitude rises above the threshold set by SD_{LVL} and de-asserts low otherwise. SD can be fed back to the enable (EN) input to maintain output stability under a loss-of-signal condition. EN de-asserts low the true output signal without removing the input signals. Typically, 4.6dB SD hysteresis is provided to prevent chattering.

Signal Detect-Level Set

A programmable signal detect-level set pin (SD_{LVL}) sets the threshold of the input amplitude detection. Connecting an external resistor between V_{CC} and SD_{LVL} sets the voltage at SD_{LVL}. This voltage ranges from V_{CC} to V_{REF}. The external resistor creates a voltage divider between V_{CC} and V_{REF} as shown in Figure 6. If desired, an appropriate external voltage may be applied rather than using a resistor. The smaller the external resistor, implying a smaller voltage difference from SD_{LVL} to V_{CC}, lowers the SD sensitivity. Hence, larger input amplitude is required to assert SD. *"Typical Operating Characteristics"* shows the relationship between the input amplitude detection sensitivity and the SD_{LVL} setting resistor.

Hysteresis

The SY88983V provides typically 4.6dB SD electrical hysteresis. By definition, a power ratio measured in dB is 10log(power ratio). Power is calculated as V_{IN}^2 /R for an electrical signal. Hence, the same ratio can be stated as 20log(voltage ratio). While in linear mode, the electrical voltage input changes linearly with the optical power and hence, the ratios also change linearly. Therefore, the optical hysteresis in dB is half the electrical hysteresis in dB given in the data sheet. The SY88983V provides typically 2.3dB SD optical hysteresis. As the SY88983V is an electrical device, this data sheet refers to hysteresis in electrical terms. With 4.6dB SD hysteresis, a voltage factor of 1.7 is required to assert SD from its de-assert value.





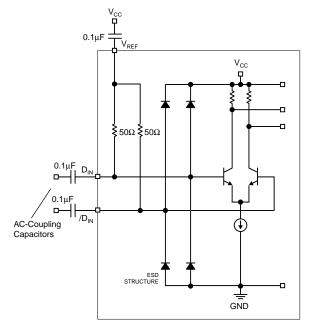


Figure 2. Input Structure

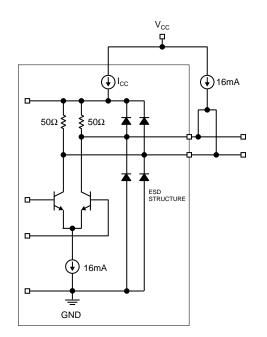


Figure 4. Power Supply Current Measurement

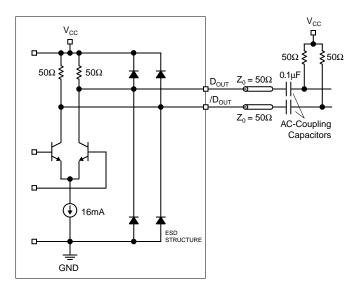


Figure 3. Output Structure

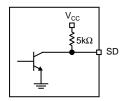


Figure 5. SD Output Structure

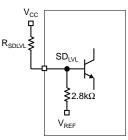
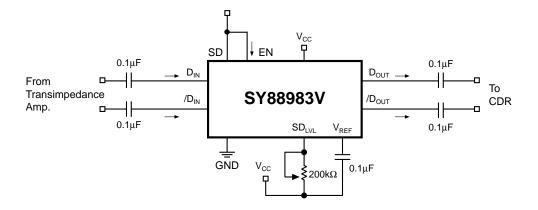
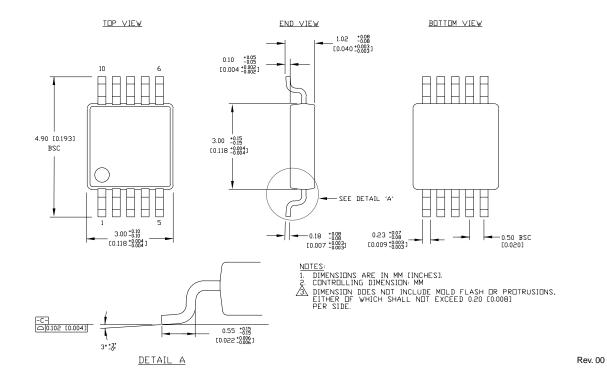


Figure 6. SD_{LVL} Setting Circuit

TYPICAL APPLICATIONS CIRCUIT

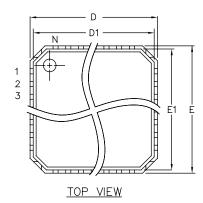


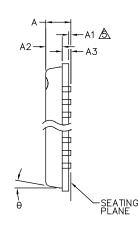
10 LEAD MSOP (K10-1)

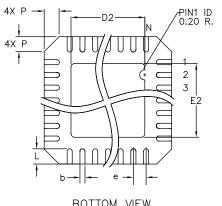


February 2005

16 LEAD *Micro*LeadFrame[™] (MLF-16)







BOTTOM VIEW

	DIMENSION (mm)			
1	MIN.	NOM.	MAX.	
A	-	0.85	1.00	
A1	0.00	0.01	0.05	
A2	-	0.65	0.80	
A3		0.20 REF.		
D		3.00 BSC		
D1		2.75 BSC		
D2	1.35	1.50	1.65	
E		3.00 BSC		
E1		2.75 BSC		
E2	1.35	1.50	1.65	
θ			12*	
Ρ	0.24	0.42	0.60	
е	0.50 BSC			
Ν		16		
L	0.30	0.40	0.50	
b	0.18	0.23	0.30	

NDTE:

- 1. 2.
- ALL DIMENSIONS ARE IN MILLIMETERS. ALL DIMENSIONS ARE IN MILLIMETERS. N IS THE NUMBER OF TERMINALS. THE NUMBER OF TERMINALS PER SIDE IS N/4. THE PINHI IDENTIFIER MUST BE EXISTED ON THE TOP SURFACE OF PACKAGE BY USING IDENTIFICATION MARK OR OTHER FEATURE OF PACKAGE BIDLY. PACKAGE WARPAGE MAX 0.05mm. З.
- Å APPLIED FOR EXPOSED PAD AND TERMINALS.

Rev.03

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